	Type	Hits	Search Text		DBs	Time S
85	BRS	1	((quantum adj (dot or wire or box)) with transistor) and (two adj top adj ga	ite) USPAT; L	JS-PGPUB	2002/08
36	BRS	0	((quantum adj (dot or wire or box)) with transistor) and (second adj top a	dj gate) USPAT, t	JS-PGPUB	2002/08
37	BRS	12	((quantum adj (dot or wire or box))with transistor) and (second adj gate)	USPAT; U	JS-PGPUB	2002/08
18	BRS	1	one adj dimensional adj flow adj electron adj gas	IBM_TDB		2002/08
99	BRS	t	(ibm with (one adj dimensional adj flow adj electron adj gas))	USPAT; L	JS-PGPUB	2002/08
80	BRS	2	*2285175*	DERWEN		2002/08
91	BRS	19	((hirotaka and kizuki).in.) and semiconductor and (mitsubishi.as.)		JS-PGPUB	2002/08
92	BRS	4	(quantum adj (dot or wire or box)) and (((hirotaka and kizuki).in.) and ser	niconductor and (mitsu_USPAT; t	JS-PGPUB	,2002/08
93	BRS	0	(quantum adj (dot or wire or box)) and (((hirotaka and kizuki).in.) and ser	niconductor and (mitsu EPO; JPC	D; DERWENT	2002/08
94	BRS	1	(quantum adj (dot or wire or box)) and (((hirotaka and kizuki) in.) and ser	niconductor and (mitsu_EPO; JP0); DERWENT	2002/08
95	BRS	1	(sakaki with (quantum adj wave adj project))		JS-PGPUB	2002/08
96	BRS	4	(quantum adj (dot or wire or box)) and (sidegate or (side adj gate))		D; DERWENT	2002/08
97	BRS	9	(quantum adj (dot or wire or box)) and ((("1deg" or (single adj electron)	or ((one adj (dimension USPAT; l	JS-PGPUB	2002/08
98	BRS	4	(("1deg" or "1 deg" or (single adj electron) or ((one adj (dimensional or	dimension)) with electr_USPAT; t	JS-PGPUB	2002/08
99	BRS	4	(("1deg" or "1 deg" or (single adj electron) or (((one or "1")adj (dimension)	onal or dimension)) with USPAT; L	JS-PGPUB	2002/08
100	BRS	2	(("1deg" or "1 deg" or (single adj electron) or (((one or "1")adj (dimensi		JS-PGPUB	2002/08
101	BRS	.1	*5316965*.PN.	USPAT		2002/08
102	BRS	:1	*4769683*.PN.	USPAT		2002/08
103	BRS	1	"4729006".PN.	USPAT		2002/08
104	BRS	5	" 5612233 "		JS-PGPUB	2002/08
105	BRS	7	(("1deg" or "1 deg" or (single ad) electron) or ((one or "1")adj (dimension	nal or dimension))) with USPAT; t	JS-PGPUB	2002/08
106	BRS	.2	((quantum adj wire) with (transistor or fet or device) not laser) and (mes	a or ridge) and (second USPAT; L	JS-PGPUB	2002/08
107	BRS	1	"5338692"		JS-PGPUB	2002/08
108	BRS	2	"5396089"	**** ** * * * * * * * **** **** * * *	JS-PGPUB	2002/08
109	BRS	3	"5701017"		JS-PGPUB	2002/08
110	BRS	2	((quantum adj wire) same (transistor or fet or device) not laser) and (me			2002/08
	BRS		((quantum adj box) same (transistor or fet or device) not laser) and (me	,	JS-PGPUB	2002/08
	BRS		((quantum adj dot) same (transistor or fet or device) not laser) and (mes		JS-PGPUB	2002/08
	BRS		(((quantum adj dot) same (transistor or fet or device) not laser) and (me			2002/08
114	BRS	9	(one adj dimensional adj channel) and (sidegate or (side adj gate))	USPAT; L	JS-PGPUB	2002/08
	BRS		"5285081"	USPAT; L	JS-PGPUB	2002/08
116	BRS	1	*5396089*.PN.	USPAT		2002/08
	BRS		"5406094".PN.	USPAT	and the second control of the second control	2002/08
	BRS		1 deg with device	USPAT		2002/08
119	BRS	14	((1deg or (single adj electron)) with device not laser) and (sidegate or (side adj gate)) USPAT		2002/08
	BRS		((1deg or (single adj electron)) with device not laser) and (backgate or (
	BRS	CO CO CO CO	"5313684".PN.		an possible to the contract of the	2002/08
	BRS		*5436191*.PN.	USPAT		2002/08
	BRS		*5607876*.PN.	USPAT		2002/08
	BRS		*5656821*.PN.	USPAT		2002/08
	BRS		"5701017",PN			2002/08
126	BRS	31	*5739056*.PN.	USPAT		2002/08
e s	ructured form	A Car	mitters A. 1975 Statey A. State Serm 子 Man 〇 Debadas 包 Houge 见 Total	USPAT		
те	Hits		Search Text DBs Time 9	Stamp Comments Error Di	efiniti Errors	

128 BRS 1 55 128 BRS 1 155 BRS 3 136 BRS 0 (1137 BRS 3 138 BRS 3 138 BRS 3 138 BRS 1 144 BRS 0 (1147 BRS 0 1448 BRS 0 1448 BRS 0 1448 BRS 0 1450 BRS 0 1450 BRS 1 1550 BRS 22 (1150 BRS 1 1550 BRS 22 1550 BRS 1 1550 BRS 22 (1150 BRS 1 1550 BRS 22 1550 BRS 23 1550 BRS 1 1550 BRS 1 1550 BRS 1 1550 BRS 1 1550 BRS 22 1550 BRS 1 1550 BRS 1 1550 BRS 1 1550 BRS 22 1550 BRS 2 1550 BRS 2 1550 BRS 2 1550 BRS 1 1550 BRS 2 1 1550 BRS 3 1	is 1770475".PN. is 28076".PN. is 28076".Po.	USPAT USPAT USPAT USPAT USPAT JPO; DERWENT JPO; DERWENT JPO; DERWENT US-PGPUB USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16
128 BRS 1 55 128 BRS 1 150 BRS 0 ("132 BRS 0 133 BRS 0 134 BRS 1 135 BRS 3 136 BRS 3 136 BRS 3 138 BRS 0 ("144 BRS 0 144 BRS 0 145 BRS 0 146 BRS 0 147 BRS 0 148 BRS 0 148 BRS 0 148 BRS 0 148 BRS 0 150 BRS 1 151 BRS 1 151 BRS 1 151 BRS 1 152 BRS 1 152 BRS 1 153 BRS 1 155 BRS 1 156 BRS 1 156 BRS 1 156 BRS 1 157 BRS 5 158 BRS 1 158 BRS 2 158 BRS 1	827754*.PN. 828076*.PN. 6313484*.PN. 6417487* "0079489*).did. and semiconductor 6417487* "0079489*).did. 6417487* "0079489*) and quantum 6417487* "0079489*) and (side adj gate) or sidegate) 6828076* One adj dimensional) with quantum not (laser or optical)) and ((side adj gate) or sidegate) 6412232* ingle adj electron adj transistor) and (v adj (shape or shaped)) ingle adj electron adj transistor) and (quantum adj wire) 682877* 68287* 68387 68387* 68387 68387 68387 68387 68387 68387 68387 68387 68387 68387 68387 68387 68387	USPAT USPAT JPO; DERWENT JPO; DERWENT JPO; DERWENT US-PGPUB USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16
129 BRS 1	828076".PN. 6417487" "0079489").did. and semiconductor 6417487" "0079489").did. 6417487" "0079489") and quantum 6417487" "0079489") and (backgate or (back adj gate)) 6828076"	USPAT JPO; DERWENT JPO; DERWENT JPO; DERWENT US-PGPUB USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16
130 BRS 1	1313484".PN. 16417487" "0079489").did. and semiconductor 16417487" "0079489").did. 16417487" "0079489") and quantum 16417487" "0079489") and quantum 16417487" "0079489") and quantum 16417487" "0079489") with device not laser) and (backgate or (back adj gate)) 16828076" 16918	USPAT JPO; DERWENT JPO; DERWENT JPO; DERWENT US-PGPUB USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16
131 BRS 0 (*132 BRS 0 (*133 BRS 0 (*134 BRS 1 (*135 BRS 3 *136 BRS 3 (*137 BRS 3 (*138 BRS 24 (*139 BRS 7 (*141 BRS 1 (*142 BRS 0 (*144 BRS 0 (*145 BRS 0 (*146 BRS 0 (*147 BRS 0 (*148 BRS 1 (*148	"6417487" "0079489").did. and semiconductor "6417487" "0079489") and quantum "1deg or (single adj electron)) with device not laser) and (backgate or (back adj gate)) "828076" "one adj dimensional) with quantum not (laser or optical)) and ((side adj gate) or sidegate) "5412232" "ingle adj electron adj transistor) and (v adj (shape or shaped)) "ingle adj electron adj transistor) and (quantum adj wire) "aser with transistor with (quantum adj wire)) "aser with (single adj electron adj transistor)) same (quantum adj wire)) "aser with (single adj electron adj field)) same (quantum adj wire)) "aser with (one adj electron)) same (quantum adj wire)) "aser with (one adj electron)) same (quantum adj wire))	JPO; DERWENT JPO; DERWENT JPO; DERWENT US-PGPUB USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16
132 BRS 0 ("133 BRS 0 ("134 BRS 1 (155 BRS 0 (154 BRS 0 (155 BRS 1 (155 BRS	"6417487" "0079489") and quantum Ideg or (single adj electron)) with device not laser) and (backgate or (back adj gate)) 828076" one adj dimensional) with quantum not (laser or optical)) and ((side adj gate) or sidegate) 5412232" ingle adj electron adj transistor) and (v adj (shape or shaped)) ingle adj electron adj transistor) and (quantum adj wire) aser with transistor with (quantum adj wire)) inser with (single adj electron adj transistor)) same (quantum adj wire)) inser with (single adj electron adj field)) same (quantum adj wire)) inser with (one adj electron)) same (quantum adj wire))	JPO; DERWENT JPO; DERWENT US-PGPUB USPAT; US-PGPUB	2002/08/10 2002/08/10 2002/08/10 2002/08/10 2002/08/10 2002/08/10 2002/08/10
133 BRS 0 (*134 BRS 1 (*135 BRS 3 *5) 136 BRS 8 (*137 BRS 3 *5) 138 BRS 3 (*137 BRS 3 *5) 138 BRS 24 (*138 BRS 7 (*138 BRS 1 (*138 BRS 0 (*138 BRS 1 (16417487" "0079489") and quantum 16 deg or (single adj electron)) with device not laser) and (backgate or (back adj gate)) 1828076" The property one adj dimensional) with quantum not (laser or optical)) and ((side adj gate) or sidegate) 15412232" Ingle adj electron adj transistor) and (v adj (shape or shaped)) Ingle adj electron adj transistor) and (quantum adj wire) Inser with transistor with (quantum adj wire)) Inser with (single adj electron adj transistor)) same (quantum adj wire)) Inser with (single adj electron adj field)) same (quantum adj wire)) Inser with (one adj electron)) same (quantum adj wire))	JPO; DERWENT US-PGPUB USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16
134 BRS 1 ((1) 135 BRS 3 "5 136 BRS 8 ((0) 137 BRS 3 (si 138 BRS 3 (si 138 BRS 7 (a) 140 BRS 7 (a) 141 BRS 0 ((a) 142 BRS 0 ((a) 144 BRS 0 ((a) 145 BRS 0 ((a) 146 BRS 0 ((a) 146 BRS 0 ((a) 147 BRS 0 ((a) 148 BRS 0 ((a) 150 BRS 22 ((a) 151 BRS 1 (si 152 BRS 1 (si 153 BRS 1 (si 154 BRS 7 (si 155 BRS 12 ((a) 157 BRS 5 ((a) 158 BRS 1 (si 158 BRS 2 (si 158 BRS 3 (si 158 BRS	Ideg or (single adj electron)) with device not laser) and (backgate or (back adj gate)) 828076* one adj dimensional) with quantum not (laser or optical)) and ((side adj gate) or sidegate) 5412232* ingle adj electron adj transistor) and (v adj (shape or shaped)) ingle adj electron adj transistor) and (quantum adj wire) aser with transistor with (quantum adj wire)) iaser with (single adj electron adj transistor)) same (quantum adj wire)) iaser with (single adj electron adj field)) same (quantum adj wire)) iaser with (one adj electron)) same (quantum adj wire))	US-PGPUB USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16
135 BRS 3	one adj dimensional) with quantum not (laser or optical)) and ((side adj gate) or sidegate) 5412232" ingle adj electron adj transistor) and (v adj (shape or shaped)) ingle adj electron adj transistor) and (quantum adj wire) aser with transistor with (quantum adj wire)) inser with (single adj electron adj transistor)) same (quantum adj wire)) inser with (single adj electron adj field)) same (quantum adj wire)) inser with 1 deg) same (quantum adj wire)) inser with (one adj electron)) same (quantum adj wire))	USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16 2002/08/16 2002/08/16
136 BRS 8 ((0 137 BRS 3 138 BRS 3 (si 138 BRS 24 (si 140 BRS 7 (la 142 BRS 0 (la 143 BRS 0 (la 144 BRS 0 (la 145 BRS 0 (la 146 BRS 0 (la 147 BRS 0 (la 148 BRS 0 (la 150 BRS 1 (si 154 BRS 7 (si 156 BRS 12 (la 156 BRS 12 (la 157 BRS 5 tra 158 BRS 1 (si 158	one adj dimensional) with quantum not (laser or optical)) and ((side adj gate) or sidegate) 5412232" ingle adj electron adj transistor) and (v adj (shape or shaped)) ingle adj electron adj transistor) and (quantum adj wire) aser with transistor with (quantum adj wire)) iaser with (single adj electron adj transistor)) same (quantum adj wire)) iaser with (single adj electron adj field)) same (quantum adj wire)) iaser with 1 deg) same (quantum adj wire)) iaser with (one adj electron)) same (quantum adj wire))	USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16 2002/08/16
137 BRS 3 (si 138 BRS 3 (si 138 BRS 24 (si 140 BRS 7 (la 141 BRS 1 (li 142 BRS 0 (li 143 BRS 0 (li 144 BRS 0 (li 146 BRS 0 (li 146 BRS 0 (li 148 BRS 0 (li 150 BRS 1 (si 153 BRS 1 (si 154 BRS 7 (si 156 BRS 12 (li 156 BRS 12 (li 156 BRS 12 (li 158 BRS 1 (si 158 BRS 1 (s	5412232" ingle adj electron adj transistor) and (v adj (shape or shaped)) ingle adj electron adj transistor) and (quantum adj wire) aser with transistor with (quantum adj wire)) aser with (single adj electron adj transistor)) same (quantum adj wire)) aser with (single adj electron adj field)) same (quantum adj wire)) aser with 1 deg) same (quantum adj wire)) aser with (one adj electron)) same (quantum adj wire))	USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB	2002/08/16 2002/08/16 2002/08/16
136 BRS 3	ingle adj electron adj transistor) and (v adj (shape or shaped)) ingle adj electron adj transistor) and (quantum adj wire) aser with transistor with (quantum adj wire)) aser with (single adj electron adj transistor)) same (quantum adj wire)) aser with (single adj electron adj field)) same (quantum adj wire)) aser with 1 deg) same (quantum adj wire)) aser with (one adj electron)) same (quantum adj wire))	USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB	2002/08/16 2002/08/16
138 BRS 3	ingle adj electron adj transistor) and (quantum adj wire) aser with transistor with (quantum adj wire)) aser with (single adj electron adj transistor)) same (quantum adj wire)) aser with (single adj electron adj field)) same (quantum adj wire)) aser with 1 deg) same (quantum adj wire)) aser with (one adj electron)) same (quantum adj wire))	USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB	2002/08/16
140 BRS 7 (la 141 BRS 1 (li 142 BRS 0 (li 143 BRS 0 (li 144 BRS 0 (li 144 BRS 0 (li 146 BRS 0 (li 147 BRS 0 (li 148 BRS 0 (li 148 BRS 0 (li 148 BRS 0 (li 150 BRS 1 (si 150 BRS 1 (si 154 BRS 1 (si 154 BRS 1 (si 155 BRS 1 (si 156 BRS 1 (si 156 BRS 1 (si 158 BRS 1 (si 15	aser with transistor with (quantum adj wire)) aser with (single adj electron adj transistor)) same (quantum adj wire)) aser with (single adj electron adj field)) same (quantum adj wire)) aser with 1 deg) same (quantum adj wire)) aser with (one adj electron)) same (quantum adj wire))	USPAT; US-PGPUB USPAT; US-PGPUB USPAT; US-PGPUB	
141 BRS 1 ((li 142 BRS 0 ((li 143 BRS 0 ((li 144 BRS 0 ((li 145 BRS 0 ((li 146 BRS 0 ((li 147 BRS 0 ((li 148 BRS 0 ((li 149 BRS 0 ((li 150 BRS 22 ((li 151 BRS 0 ((li 152 BRS 5 ((li 153 BRS 1 (si 154 BRS 7 (si 155 BRS 12 ((li 156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 1 sa 158 BRS 1 sa 168 BRS 2 rid	aser with (single adj electron adj transistor)) same (quantum adj wire)) aser with (single adj electron adj field)) same (quantum adj wire)) aser with 1 deg) same (quantum adj wire)) aser with (one adj electron)) same (quantum adj wire))	USPAT; US-PGPUB USPAT; US-PGPUB	:2002/08/T
142 BRS 0 ((late) 143 BRS 0 ((late) 144 BRS 0 ((late) 145 BRS 0 ((late) 146 BRS 0 ((late) 147 BRS 0 ((late) 148 BRS 0 ("late) 148 BRS 0 ("late) 150 BRS 22 ((late) 151 BRS 0 ((late) 152 BRS 5 ((late) 153 BRS 1 (since) 154 BRS 7 (since) 155 BRS 12 ("late) 156 BRS 22 (elate) 157 BRS 5 train 158 BRS 21 train 158 BRS 21 train 159 BRS 1 sanction 160 BRS 1 sanction 161 BRS 14 quality 162 BRS 3 minutes 163 BRS 2 rid	aser with (single adj electron adj field)) same (quantum adj wire)) aser with 1 deg) same (quantum adj wire)) aser with (one adj electron)) same (quantum adj wire))	USPAT; US-PGPUB	• • •
143 BRS 0 ((late 144 BRS 0) (late 145 BRS 0) (late 146 BRS 0) (late 147 BRS 0) (late 148 BRS 0) (late 148 BRS 0) (late 148 BRS 0) (late 148 BRS 0) (late 150 BRS 22) (late 150 BRS 22) (late 151 BRS 0) (late 152 BRS 5) (late 153 BRS 1) (since 154 BRS 7) (since 156 BRS 12) (late 157 BRS 5) (late 158 BRS 21) (late 158 BRS 21) (late 158 BRS 4) (late 158 BRS 4) (late 158 BRS 1) (late 158 BR	aser with 1 deg) same (quantum adj wire)) aser with (one adj electron)) same (quantum adj wire))		2002/08/16
144 BRS 0 ((la 145 BRS 0) (la 146 BRS 0) (la 147 BRS 0) (la 148 BRS 0) (la 148 BRS 0) (la 150 BRS 22) (la 151 BRS 0) (la 151 BRS 1) (si 152 BRS 1) (si 155 BRS 12) (la 156 BRS 12) (la 158 BRS 21) (la 158 BRS 1) (la 168 BRS 2) (la 16	aser with (one adj electron)) same (quantum adj wire))		2002/08/16
145 BRS 0 (la 146 BRS 0 (la 147 BRS 0 (pl 148 BRS 0 (pl 148 BRS 0 (pl 149 BRS 0 (pl 150 BRS 22 (l) 151 BRS 0 (l) 152 BRS 5 (l) 153 BRS 1 (si 154 BRS 7 (si 155 BRS 12 (pl 156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 21 tra 158 BRS 1 sa 161 BRS 14 qu 162 BRS 3 mi 163 BRS 2 rid		USPAT; US-PGPUB	2002/08/16
146 BRS 0 (la 146 BRS 0 (la 147 BRS 0 (pl 148 BRS 0 (pl 148 BRS 0 (pl 150 BRS 22 (pl 151 BRS 0 (pl 152 BRS 5 (pl 153 BRS 1 (si 154 BRS 7 (si 155 BRS 12 (pl 156 BRS 22 (pl 157 BRS 5 tra 158 BRS 21 tra 158 BRS 2 (pl 158 BRS 1 (p		USPAT; US-PGPUB	2002/08/16
146 BRS 0 ((late 147 BRS 0 (plane) 148 BRS 0 (plane) 148 BRS 0 (plane) 150 BRS 22 (plane) 151 BRS 0 (plane) 152 BRS 5 (plane) 153 BRS 1 (plane) 154 BRS 7 (plane) 156 BRS 12 (plane) 157 BRS 5 (plane) 158 BRS 21 (plane) 158 BRS 1 (plane) 158 BRS 1 (plane) 158 BRS 1 (plane) 160 BRS 1 (plane) 161 BRS 14 (plane) 162 BRS 3 (plane) 163 BRS 2 (plane) 163 BRS 2 (plane) 164 BRS 3 (plane) 165 BRS 2 (plane) 165 BRS 3 (plane) 165 BRS 2 (plane) 165 BRS 3 (plane) 165	aser with set with (quantum adj wire))	USPAT; US-PGPUB	2002/08/16
147 BRS 0 (pl 148 BRS 0 (" 149 BRS 0 (" 150 BRS 22 ((" 151 BRS 0 ((" 152 BRS 5 ((" 153 BRS 1 (si 154 BRS 7 (si 156 BRS 12 (" 156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 4 mi 158 BRS 1 sa 160 BRS 1 sa 161 BRS 14 qui 162 BRS 3 mi	aser with set) same (quantum adj wire))	USPAT; US-PGPUB	2002/08/10
148 BRS 0 ("149 BRS 0 ("150 BRS 22 (("151 BRS 0 ("152 BRS 5 (("153 BRS 1 (si 154 BRS 7 (si 155 BRS 12 ("156 BRS 12 ("156 BRS 22 (el 157 BRS 5 trains 158 BRS 21 trains 158 BRS 1 (si 168	lane with "(111)" with since with grow with groove) and semiconductor	USPAT; US-PGPUB	2002/08/16
149 BRS 0 (" 150 BRS 22 (() 151 BRS 0 () 152 BRS 5 (() 153 BRS 1 (si 154 BRS 7 (si 156 BRS 12 () 156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 4 mid 160 BRS 1 sa 161 BRS 14 quid 162 BRS 3 mid 163 BRS 2 rid	'(111)" with since with grow with groove) and semiconductor	USPAT; US-PGPUB	2002/08/19
150 BRS 22 ((151 BRS 0 (152 BRS 5 (153 BRS 1 (55 BRS 12 (155 BRS 12 (155 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 1 sa 168 BRS 1 sa 168 BRS 1 sa 168 BRS 2 rid	'(111)" with since with groove) and semiconductor	USPAT; US-PGPUB	2002/08/16
151 BRS 0 (('152 BRS 5 ('153 BRS 1 (si 154 BRS 7 (si 155 BRS 12 ("156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 4 miles 158 BRS 1 sa 160 BRS 1 sa 160 BRS 1 sa 160 BRS 1 miles 160 BRS 2 miles 160 BRS 3	"(111)" with groove) same "(011)") and semiconductor	USPAT; US-PGPUB	2002/08/16
152 BRS 5 ((153 BRS 1 (si 154 BRS 7 (si 155 BRS 12 ("156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 159 BRS 4 min 160 BRS 1 sa 161 BRS 14 qui 162 BRS 3 min 163 BRS 2 rid	"(111)" with groove) same "(011)") and semiconductor and gasas and algaas	USPAT; US-PGPUB	2002/08/10
153 BRS 1 (si 154 BRS 7 (si 156 BRS 12 (" 156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 4 mi 159 BRS 1 sa 160 BRS 1 sa 161 BRS 14 qu 162 BRS 3 mi 163 BRS 2 rid	"(111)" with groove) same "(011)") and semiconductor and gaas and algaes	USPAT; US-PGPUB	2002/08/10
154 BRS 7 (si 155 BRS 12 (" 156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 4 mi 160 BRS 1 sa 161 BRS 14 qu 162 BRS 3 mi 163 BRS 2 rid	to the state of th	USPAT; US-PGPUB	2002/08/19
156 BRS 12 (" 156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 4 mi 160 BRS 1 sa 161 BRS 14 qu 162 BRS 3 mi 163 BRS 2 rid		USPAT; US-PGPUB	2002/08/19
156 BRS 22 (el 157 BRS 5 tra 158 BRS 21 tra 158 BRS 4 mi 160 BRS 1 sa 161 BRS 14 qu 162 BRS 3 mi 163 BRS 2 rid	ingle adj electron adj (transistor or field)) same (quantum adj wire)	USPAT; US-PGPUB	2002/08/19
157 BRS 5 tra 158 BRS 21 tra 158 BRS 4 mi 160 BRS 1 sa 161 BRS 14 qu 162 BRS 3 mi 163 BRS 2 rid	(111)" with groove) and hemt	USPAT; US-PGPUB	2002/08/19
158 BRS 21 tra 158 BRS 4 mi 160 BRS 1 sa 161 BRS 14 qu 162 BRS 3 mi 163 BRS 2 rid	lectron adj gas) with (quantum adj wire)		2002/08/19
158 BRS 4 mi 160 BRS 1 sa 161 BRS 14 qu 162 BRS 3 mi 163 BRS 2 rid	ansistor same ((electron adj gas) with (quantum adj wire))	USPAT; US-PGPUB	2002/08/19
160 BRS 1 sa 161 BRS 14 qu 162 BRS 3 mo 163 BRS 2 rid	ansistor same (channel with (quantum adj wire)) esa and (transistor same (channel with (quantum adj wire)))	USPAT; US-PGPUB	
161 BRS 14 qu 162 BRS 3 mo 163 BRS 2 rid			2002/08/19
162 BRS 3 mg 163 BRS 2 rid	akaki with (sidegate or (side adj gate))	USPAT; US-PGPUB	2002/08/19
163 BRS 2 rid	uantum with (sidegate or (side adj gate)) esa and (quantum with (sidegate or (side adj gate)))	USPAT; US-PGPUB	2002/08/19
I 103 BKS Z NO	esa and (quantum with (sidegate or (side adj gate)))	USPAT; US-PGPUB	2002/08/19
d 1001 dellocate cool as as as a second second	ige and (quantum with (sidegate or (side adj gate)))	USPAT; US-PGPUB	2002/08/19
11: 01: 04: 10: 10: 10: 10: 10: 10: 10: 10: 10: 10	872038".PN.	USPAT	2002/08/19
165 BRS 1 '5	198879°.PN.	USPAT	2002/08/19
	475237°.PN.	USPAT	2002/08/19
167 BRS 1 5	512762*.PN.	00171	2002/08/19
168 BRS 7 (si	idegate or (side adj gate)) and ("gate 2") and electron and (mesa or ridge)	USPAT; US-PGPUB	2002/08/19
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